

DARLINGTON POWER TRANSISTOR 2SC4810

NPN SILICON EPITAXIAL TRANSISTOR (DARLINGTON CONNECTION) FOR HIGH-SPEED SWITCHING

The 2SC4810 is a high-speed Darlington power transistor. This transistor is ideal for high-precision control such as PWM control for pulse motors or brushless motors in OA and FA equipment.

In addition, this transistor features a package that can be auto-mounted in radial taping specifications, thus contributing to mounting cost reduction.

FEATURES

- · Auto-mounting possible in radial taping specifications
- · Resin-molded insulation type package with power rating of 1.8 W in stand-alone conditions
- · On-chip C-to-E reverse diode
- · Fast switching speed

ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

Parameter	Symbol	Ratings	Unit
Collector to base voltage	Vcво	100	V
Collector to emitter voltage	VCEO	100	V
Emitter to base voltage	VEBO	8.0	V
Collector current (DC)	Ic(DC)	±5.0	Α
Collector current (pulse)	IC(pulse)*	±10	Α
Base current (DC)	I _{B(DC)}	0.5	Α
Total power dissipation	Рт	1.8	W
Junction temperature	Tj	150	°C
Storage temperature	T _{stg}	−55 to +150	°C

^{*} PW \leq 300 μ s, duty cycle \leq 10%

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ELECTRICAL CHARACTERISTICS (Ta = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector to emitter voltage	VCEO(SUS)	Ic = 5 A, I _B = 5 mA, L = 180 μ H	100			V
Collector to emitter voltage	VCEX(SUS)	$I_C = 5 \text{ A}, I_B = 5 \text{ mA}$ L = 180 μ H, clamped	100			V
Collector cutoff current	Ісво	V _{CB} = 100 V, I _E = 0			1.0	μΑ
Emitter cutoff current	ІЕВО	V _{EB} = 5 V, I _C = 0			5.0	mA
DC current gain	h _{FE1} *	Vce = 2.0 V, Ic = 2.0 A	2,000		20,000	_
DC current gain	h _{FE2} *	Vce = 2.0 V, Ic = 4.0 A	500			-
Collector saturation voltage	V _{CE(sat)} *	Ic = 2.0 A, I _B = 2.0 mA		0.9	1.5	V
Base saturation voltage	V _{BE(sat)} *	Ic = 2.0 A, I _B = 2.0 mA		1.5	2.0	V
Turn-on time	ton	$Ic = 2.0 \text{ A}, I_{B1} = -I_{B2} = 2.0 \text{ mA}$		0.5		μs
Storage time	tstg	RL = 25Ω , Vcc $\cong 50 \text{ V}$ Refer to the test circuit.		2.5		μs
Fall time	tf	nelei to the test cricuit.		0.6		μs

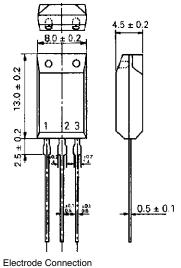
^{*} Pulse test PW \leq 350 μ s, duty cycle \leq 2%

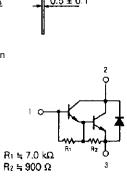
hfe CLASSIFICATION

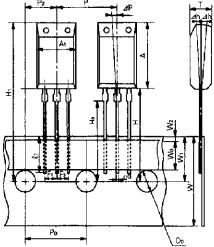
Marking	М	L	К
h _{FE1}	2,000 to 5,000	4,000 to 10,000	8,000 to 20,000

PACKAGE DRAWING (UNIT: mm)

TAPING SPECIFICATION





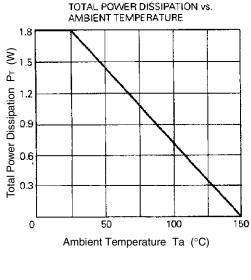


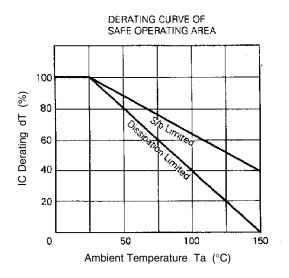
A ₁	8.0 ± 0.2
Α	13.0 ± 0.2
D٥	$\phi 4.0 \pm 0.2$
d	0.5 ± 0.1
Fı	2.5+0.4
F ₂	2.5+0.4
Н	20.0 MAX.
He	16.0 ± 0.5
Hi	32.2 MAX.
⊿h	0 ± 1.0
L1	2.5 MIN.
Р	12.7 ± 1.0
Po	12.7 ± 0.3
P₂	6.35 ± 0.5
⊿P	0 ± 1.3
T	4.5 ± 0.2
W	18.0±1.0 0.5
Wa	5.0 MIN.
W_1	9.0 ± 0.5
W_2	0.7 MIN.
	<u> </u>

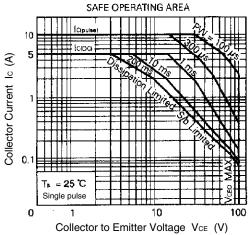
Base
 Collector
 Emitter

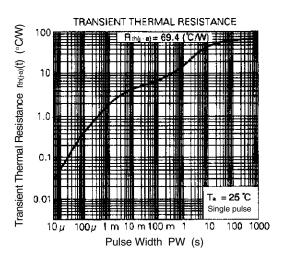


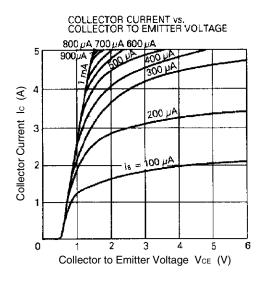
查询"280 CXLU"(共区F CTERISTICS (Ta = 25°C)

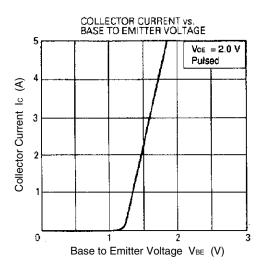








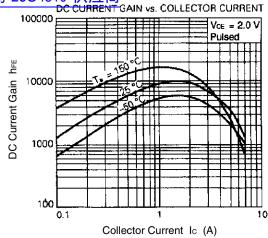


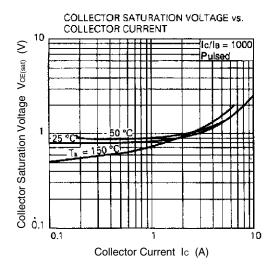


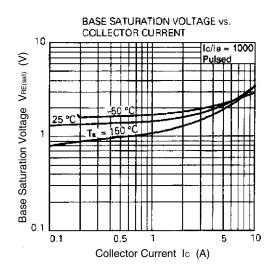
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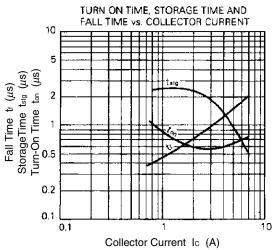


查询"2SC4810"供应商



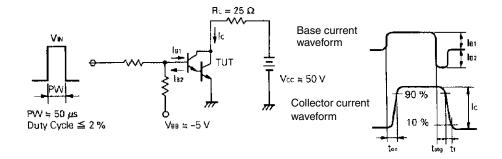








查询SWOPCHIN供应麻 (ton, tstg, tf) TEST CIRCUIT



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